NSN 5961-00-997-1319

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80131-release4401 professional/industrial association specification

Shelf Life:

N/a

inclosure material:
Metal
Overall Length:
0.757 inches
End Application:
Nimitz class cvn, emory s. Land class as, tarawa class lha, oliver perry class ffg. Submarine miscellaneous sonar and adp systems.
An/bqs-14a/15 sonar sets. 2m/ate microminiature automatic test equipment. P-3 orion fms aircraft. Deep submergence systems programs
(dssp).
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
155.0 breakdown voltage, collector-to-base, emitter open and 7.0 breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
Between 200.00 milliamperes source cutoff current and 1.00 amperes source cutoff current
Power Rating Per Characteristic:
15.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Weapon system essential. Features - junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 3 uninsulated wire lead
Specification Data:

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Demilitarization:

No

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